

GP1A30R

OPIC Photointerrupter with Encoder Function

■ Features

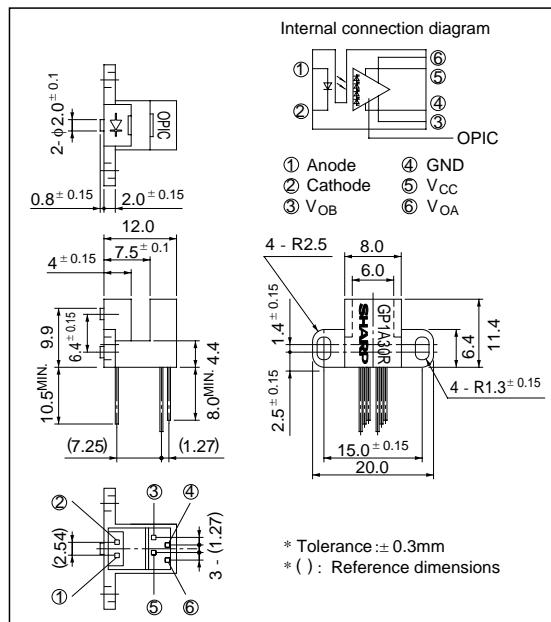
1. 2-phase (A, B) digital output
2. Possible to use plastic disk
3. High sensing accuracy
(Disk slit pitch : 0.7mm)
4. TTL compatible output
5. Compact and light

■ Applications

1. Electronic typewriters, printers
2. Numerical control machines

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings (Ta = 25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	65	mA
	* ¹ Peak forward current	I _{FM}	1	A
	Reverse voltage	V _R	6	V
	Power dissipation	P	100	mW
Output	Supply voltage	V _{CC}	7	V
	Low level output current	I _{OL}	20	mA
	Power dissipation	P _O	250	mW
Operating temperature		T _{opr}	0 to + 70	°C
Storage temperature		T _{sig}	- 40 to + 80	°C
* ² Soldering temperature		T _{sol}	260	°C

*1 Pulse width <= 100μs, Duty ratio= 0.01

*2 For 5 seconds

■ Electro-optical Characteristics

(Unless otherwise specified, Ta = 0 to + 70°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	Ta = 25°C, I _F = 30mA	-	1.2	1.5	V
	Reverse current	I _R	Ta = 25°C, V _R = 3V	-	-	10	μ A
Output	Operating supply voltage	V _{CC}		4.5	5.0	5.5	V
	High level output voltage	V _{OH}	* ³ V _{CC} = 5V, I _F = 30mA	2.4	4.9	-	V
	Low level output voltage	V _{OL}	* ³ I _{OL} = 8mA, V _{CC} = 5V, I _F = 30mA	-	0.1	0.4	V
	Supply current	I _{CC}	* ³ * ⁴ I _F = 30mA, V _{CC} = 5V	-	5	20	mA
Transfer characteristics	Duty ratio	* ⁵ D _A	V _{CC} = 5V, I _F = 30mA,	20	50	80	%
		* ⁵ D _B	* ³ f = 2.5kHz	20	50	80	%
	Response frequency	f _{MAX.}	* ³ V _{CC} = 5V, I _F = 30mA	-	-	5	kHz

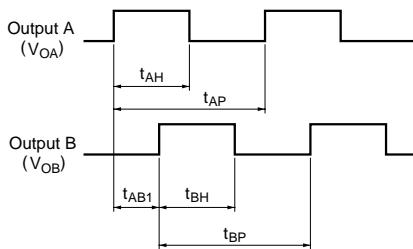
*3 Measured under the condition shown in Measurement Conditions.

*4 In the condition that output A and B are low level.

*5

$$D_A = \frac{t_{AH}}{t_{AP}} \times 100, \quad D_B = \frac{t_{BH}}{t_{BP}} \times 100$$

■ Output Waveforms



Rotational direction: Counterclockwise when seen from OPIC light detector

Fig. 1 Forward Current vs. Ambient Temperature

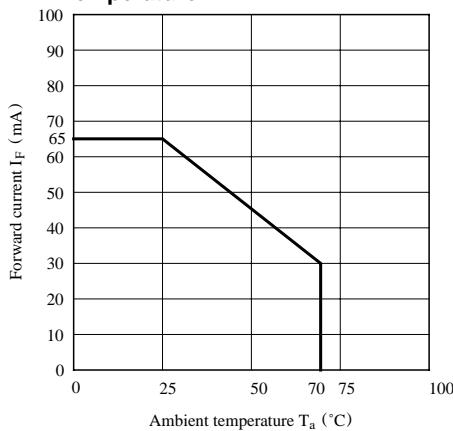


Fig. 2 Output Power Dissipation vs. Ambient Temperature

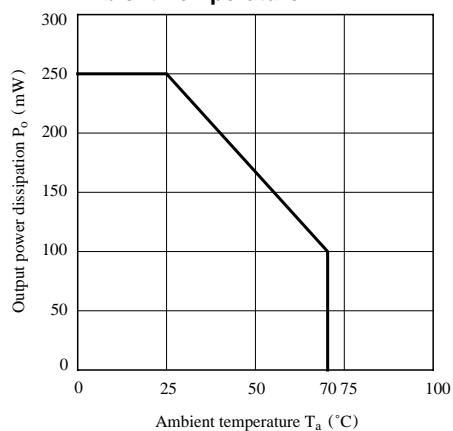


Fig. 3 Duty Ratio vs. Frequency

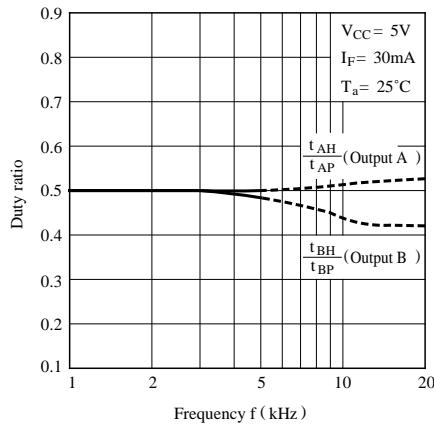


Fig. 4 Phase Difference vs. Frequency

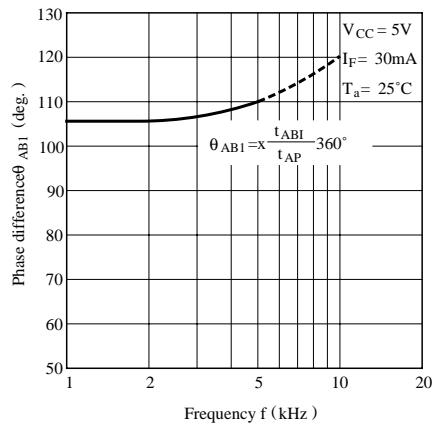


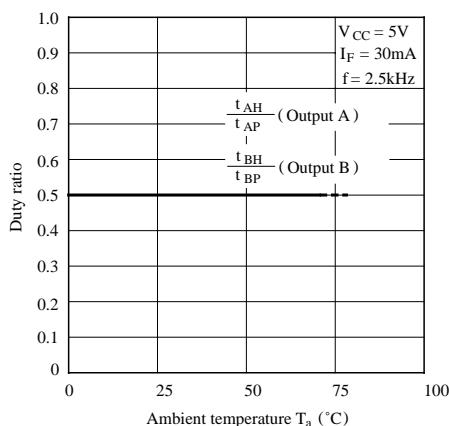
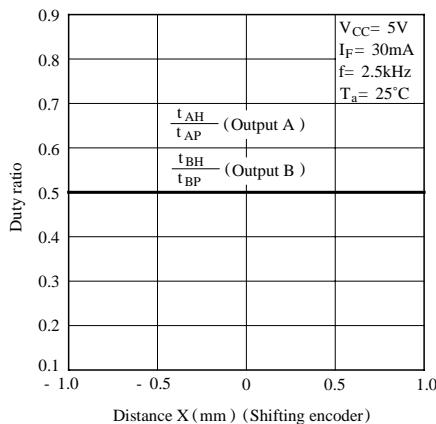
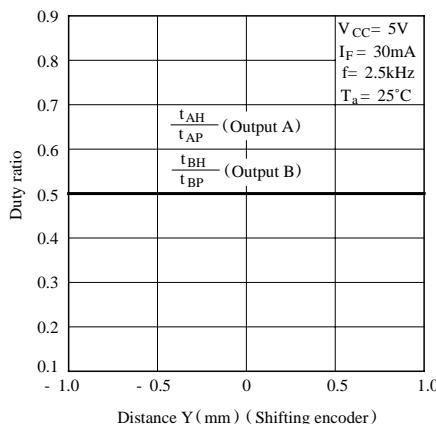
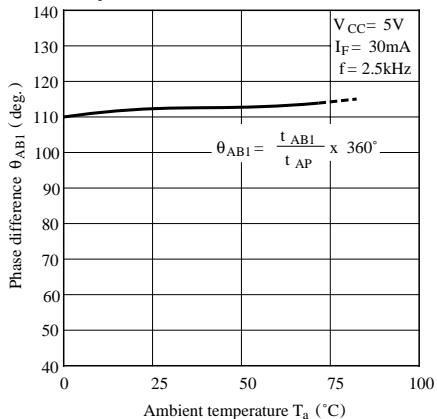
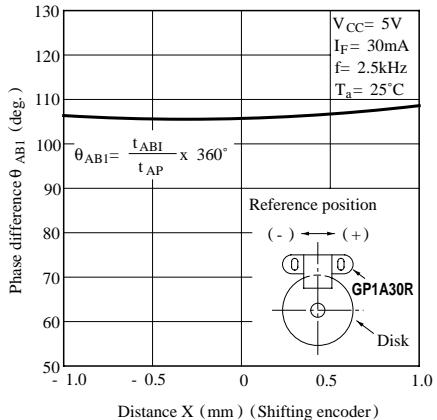
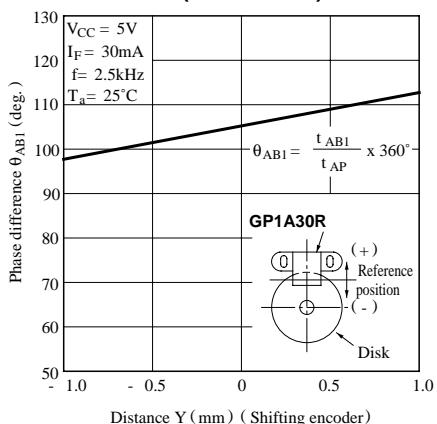
Fig. 5 Duty Ratio vs. Ambient Temperature**Fig. 7 Duty Ratio vs. Distance (X direction)****Fig. 9 Duty Ratio vs. Distance (Y direction)****Fig. 6 Phase Difference vs. Ambient Temperature****Fig. 8 Phase Difference vs. Distance (X direction)****Fig. 10 Phase Difference vs. Distance (Y direction)**

Fig.11 Duty Ratio vs. Distance (Z direction)

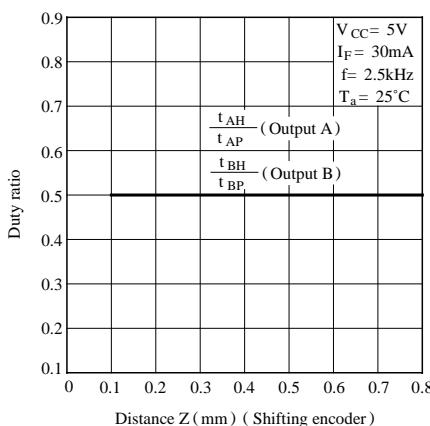
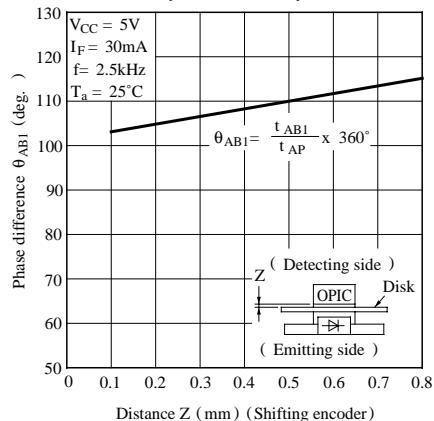
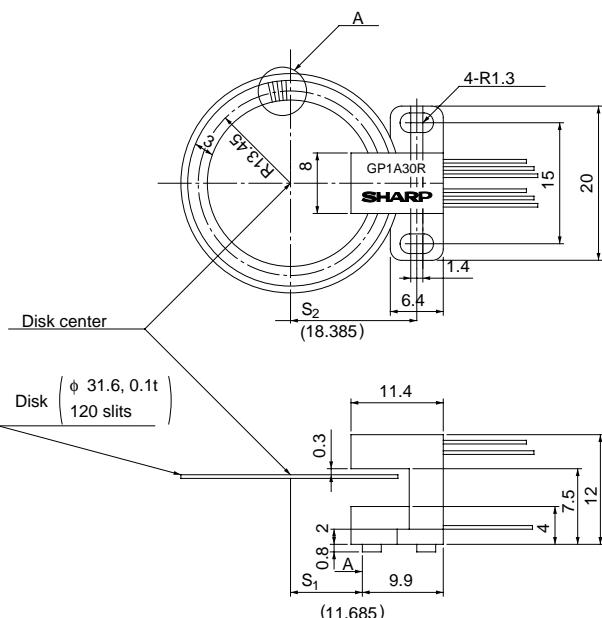


Fig.12 Phase Difference vs. Distance (Z direction)



■ Measurement Conditions



■ Precautions for Use

- (1) This module is designed to be operated at $I_F = 30\text{mA TYP.}$
 - (2) Fixing torque : MAX. $0.6\text{Nm (6kgf} \cdot \text{cm)}$
 - (3) In order to stabilize power supply line, connect a by-pass capacitor of more than $0.01\mu\text{F}$ between Vcc and GND near the device.
 - (4) As for other general cautions, refer to the chapter "Precautions for Use".

<Basic Design>

R_O (distance between the disk center and half point of a slit), P (slit pitch), S_1 and S_2 (installing position of photointerrupter) will be provided by the following equations.

Slit pitch: P (slit center)

$$P = \frac{2x p x R_0}{(mm)}$$

$$S := B_+ - 1.765 \text{ (mm)}, \quad S := S_+ + 6.7 \text{ (mm)}$$

Note) When the number of slits is changed, values in parenthesis
are also changed according to the number.

(Ex.) In the case of
N= 200P/R

$$R_O = \frac{200}{120} \times 13.45 \text{ (mm)} \\ = 22.42 \text{ mm}$$

$$P = \frac{2 \times p \times 22.42}{200} \text{ (mm)}$$

$S_1 = 22.42 \pm 1.76$

$$S_3 = 20.655 \pm 6.7$$

$$= 27.355\text{mm}$$

